NSN 5961-01-341-9618

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Inclosure Material:

Metal

Overall Length:

1.573 inches

Overall Height:

0.320 inches

Overall Width:

1.050 inches

Function For Which Designed:

Switching

Mounting Facility Quantity:

2

Internal Configuration:

Field effect

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-204ae

Electrode Internally-electrically Connected To Case:

Drain

Mounting Method:

Unthreaded hole

Features Provided:

Electrostatic sensitive and hermetically sealed case and quality assurance level tx

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

200.0 drain to gate voltage and 200.0 drain to source voltage

Current Rating Per Characteristic:

30.00 amperes detector signal current

Power Rating Per Characteristic:

150.0 watts total power dissipation

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Terminal Type And Quantity:

1 case and 2 pin

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0